| ΡΛΝ | JIT       |
|-----|-----------|
|     | SEMI      |
|     | CONDUCTOR |



### 60V P-Channel Enhancement Mode MOSFET

Current

-1.9A

### Features

Voltage

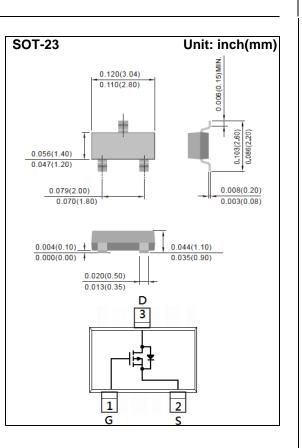
•  $R_{DS(ON)}$ ,  $V_{GS}$ @-10V,  $I_D$ @-1.9A<170m $\Omega$ 

-60 V

- $R_{DS(ON)}$ ,  $V_{GS}$ @-4.5V,  $I_D$ @-1.5A<220m $\Omega$
- Advanced Trench Process Technology
- Specially Designed for Switch Load, PWM Application, etc
- AEC-Q101 qualified
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

#### **Mechanical Data**

- Case: SOT-23 Package
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.0003 ounces, 0.0084 grams



### Maximum Ratings and Thermal Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

| PARAMETER   | R                    | SYMBOL                           | LIMIT       | UNITS |  |
|---|----------------------|----------------------------------|-------------|-------|--|
| Drain-Source Voltage  |                      | V <sub>DS</sub>                  | -60         | - V   |  |
| Gate-Source Voltage   |                      | V <sub>GS</sub>                  | <u>+</u> 20 |       |  |
| Continuous Drain Current (Note 4)   | T <sub>A</sub> =25°C |                                  | -1.9        | A     |  |
|   | T <sub>A</sub> =70°C | I <sub>D</sub>                   | -1.5        |       |  |
| Pulsed Drain Current (Note 1)   |                      | I <sub>DM</sub>                  | -7.6        |       |  |
| Power Dissipation   | T <sub>A</sub> =25°C | _                                | 1.25        | W     |  |
|   | T <sub>A</sub> =70°C | PD                               | 0.8         |       |  |
| Single Pulse Avalanche Energy (Note 6)                                    |                      | E <sub>AS</sub>                  | 32          | mJ    |  |
| Operating Junction and Storage Temperature Range                          |                      | T <sub>J</sub> ,T <sub>STG</sub> | -55~150     | °C    |  |
| Typical Thermal Resistance<br>- Junction to Ambient <sup>(Note 4,5)</sup> |                      | R <sub>θJA</sub>                 | 100         | °C/W  |  |

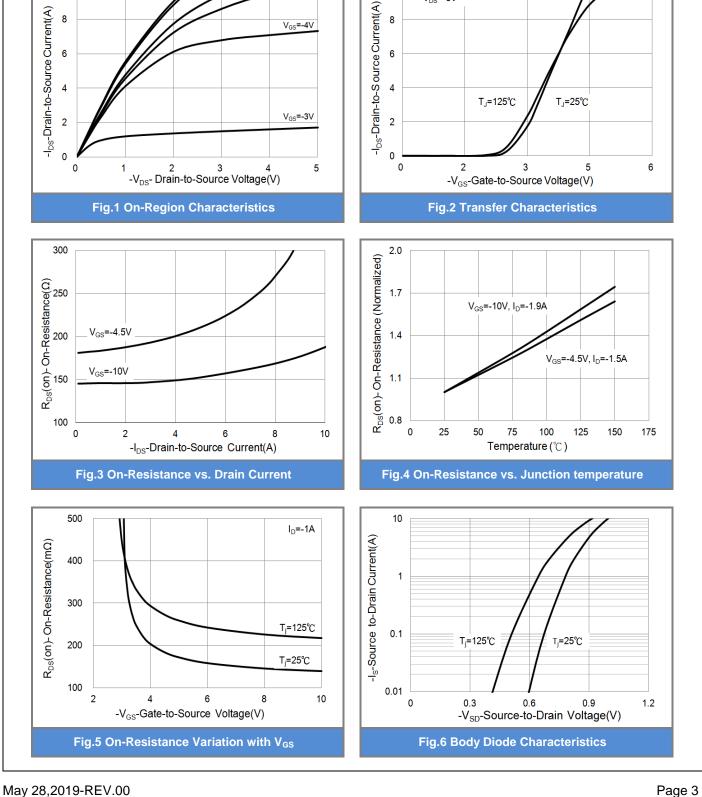


### **Electrical Characteristics** ( $T_A=25^{\circ}C$ unless otherwise noted)

| PARAMETER  | SYMBOL              | TEST CONDITION   | MIN. | TYP.  | MAX.         | UNITS |
|--|---------------------|--|------|-------|--------------|-------|
| Static   |                     |  |      |       |              |       |
| Drain-Source Breakdown Voltage   | $BV_{DSS}$          | V <sub>GS</sub> =0V, I <sub>D</sub> =-250uA  | -60  | -     | -            | v     |
| Gate Threshold Voltage   | V <sub>GS(th)</sub> | $V_{DS}=V_{GS}$ , $I_{D}=-250$ uA  | -1   | -1.88 | -2.5         | V     |
| Drain-Source On-State Resistance   | $R_{DS(on)}$        | V <sub>GS</sub> =-10V, I <sub>D</sub> =-1.9A   | -    | 140   | 170          |       |
|  |                     | V <sub>GS</sub> =-4.5V, I <sub>D</sub> =-1.5A  | -    | 190   | 220          | mΩ    |
| Zero Gate Voltage Drain Current  | I <sub>DSS</sub>    | V <sub>DS</sub> =-60V, V <sub>GS</sub> =0V   | -    | -     | -1           | uA    |
| Gate-Source Leakage Current  | I <sub>GSS</sub>    | V <sub>GS</sub> = <u>+</u> 12V, V <sub>DS</sub> =0V  | -    | -     | <u>+</u> 100 | nA    |
| Dynamic (Note 7)   |                     |  |      |       |              |       |
| Total Gate Charge  | $Q_{g}$             | V <sub>DS</sub> =-30V, I <sub>D</sub> =-1.9A,<br>V <sub>GS</sub> =-10V <sup>(Note 2,3)</sup>         | -    | 8.3   | -            | nC    |
| Gate-Source Charge   | $Q_gs$              |  | -    | 1.8   | -            |       |
| Gate-Drain Charge  | $Q_gd$              |  | -    | 1.6   | -            |       |
| Input Capacitance  | Ciss                | V <sub>DS</sub> =-30V, V <sub>GS</sub> =0V,<br>f=1.0MHZ  | -    | 430   | -            | _     |
| Output Capacitance   | Coss                |  | -    | 33    | -            | pF    |
| Reverse Transfer Capacitance   | Crss                |  | -    | 29    | -            |       |
| Turn-On Delay Time   | td <sub>(on)</sub>  | $V_{DD}$ =-30V, I <sub>D</sub> =-1A,<br>$V_{GS}$ =-10V,<br>$R_{G}$ =6 $\Omega$ <sup>(Note 2,3)</sup> | -    | 5.1   | -            |       |
| Turn-On Rise Time  | tr                  |  | -    | 20    | -            |       |
| Turn-Off Delay Time  | td <sub>(off)</sub> |  | -    | 36    | -            | ns    |
| Turn-Off Fall Time   | tf                  |  | -    | 11    | -            |       |
| Drain-Source Diode   |                     |  | _    |       |              |       |
| Maximum Continuous Drain-Source<br>Diode Forward Current <sup>(Note 3)</sup> | I <sub>S</sub>      |  | -    | -     | -1.5         | A     |
| Diode Forward Voltage  | $V_{SD}$            | I <sub>S</sub> =-1A, V <sub>GS</sub> =0V   | -    | -0.78 | -1           | V     |

NOTES :

- 1. Pulse width <300us, Duty cycle <2%
- 2. Essentially independent of operating temperature typical characteristics.
- Repetitive rating, pulse width limited by junction temperature T<sub>J(MAX)</sub>=150°C. Ratings are based on low frequency and duty cycles to keep initial T<sub>J</sub> =25°C.
- 4. The maximum current rating is package limited.
- 5. R<sub>OJA</sub> is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch<sup>2</sup> with 2oz.square pad of copper.
- 6. The test condition is L=1mH,  $I_{AS} {=} {-}8A, \, V_{DD} {=} {-}25V, \, V_{GS} {=} {-}10V.$
- 7. Guaranteed by design, not subject to production testing.



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V<sub>DS</sub>=-5V

# **PJA3461-AU**

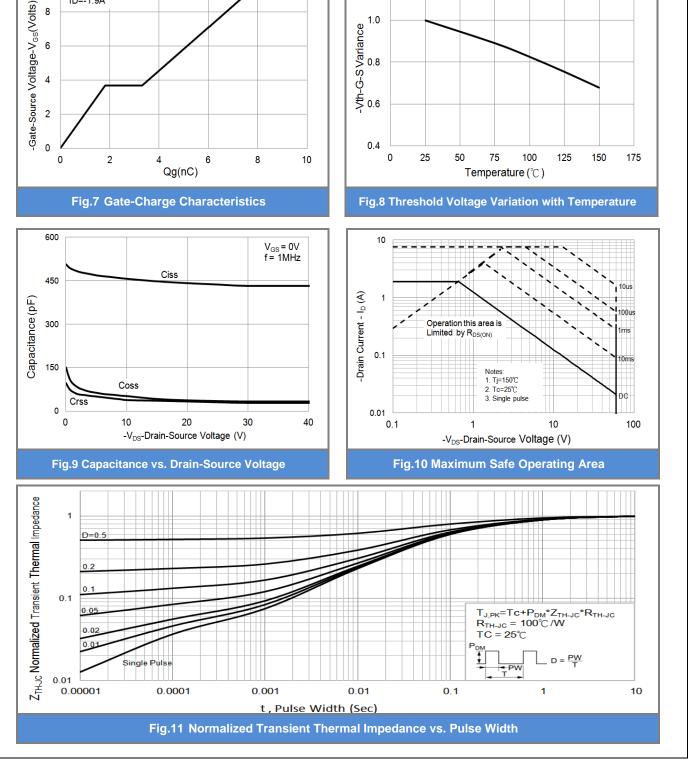
V<sub>GS</sub>=-10V,-8V

**TYPICAL CHARACTERISTIC CURVES** 

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May 28,2019-REV.00



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### PANJ SEMI CONDUCTOR

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**PJA3461-AU** 

V<sub>DS</sub>=-30V ID=-1.9A



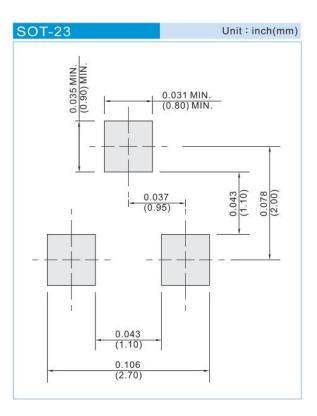
I<sub>D</sub>=-250uA



### Part No Packing Code Version

| Part No Packing Code | Package Type | Packing Type     | Marking | Version      |
|----------------------|--------------|------------------|---------|--------------|
| PJA3461-AU_R1_000A1  | SOT-23       | 3K pcs / 7" reel | A61     | Halogen free |

### Packaging Information & Mounting Pad Layout





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